

Switch - N-Channel MMBF5103

Features

- This Device is Designed for Low Level Analog Switching, Sample and Hold Circuits and Chopper Stabilized Amplifiers
- Sourced from Process 51
- See J111 for Characteristics
- This is a Pb-Free and Halide Free Device

ABSOLUTE MAXIMUM RATINGS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.) (Notes 1 and 2)

| Symbol | Parameter | Value | Unit |
|-----------------------------------|---|------------|------|
| V_{DG} | Drain-Gate Voltage | 40 | V |
| V _{GS} | Gate-Source Voltage | -40 | V |
| I _{GF} | Forward Gate Current | 50 | mA |
| T _J , T _{STG} | Operating and Storage Junction Temperature Range | -55 to 150 | °C |

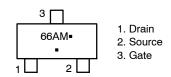
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.



SO1-23 CASE 318-08

MARKING DIAGRAM



66A = Specific Device Code

M = Date Code

= Pb-Free Package

ORDERING INFORMATION

| Device | Package | Shipping |
|----------|--------------------------------------|-----------------------|
| MMBF5103 | SOT-23 (Pb-Free / Halide Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

THERMAL CHARACTERISTICS (Values are at T_A = 25°C unless otherwise noted.) (Note 3)

| Symbol | Parameter | Value | Unit |
|----------------|---|-------|-------|
| P _D | Total Device Dissipation | 350 | mW |
| | Derate Above 25°C | 2.8 | mW/°C |
| $R_{	heta JA}$ | Thermal Resistance, Junction-to-Ambient | 357 | °C/W |

^{3.} Device mounted on FR-4 PCB 36 mm \times 18 mm \times 1.5 mm; mounting pad for the collector lead minimum 6 cm².

ELECTRICAL CHARACTERISTICS Values are at T_A = 25°C unless otherwise noted.

| Symbol | Parameter | Test Conditions | Min | Max | Unit |
|-----------------------|--|---|--------------|------|--------------|
| OFF CHARAC | TERISTICS | | | | |
| V _{(BR)GSS} | Gate-Source Breakdown Voltage | $I_G = 1.0 \mu A, V_{DS} = 0$ | -40 | - | V |
| I _{GSS} | Gate Reverse Current | $V_{GS} = -15 \text{ V}, V_{DS} = 0$ | - | -200 | pА |
| | | $V_{GS} = -15 \text{ V}, V_{DS} = 0, T_A = 125^{\circ}\text{C}$ | - | -500 | nA |
| V _{GS} (off) | Gate-Source Cut-Off Voltage | V _{DS} = 20 V, I _D = 1.0 nA | -1.2 | -2.7 | V |
| V _{GS} (f) | Gate-Source Forward Voltage | I _G = 1.0 mA, V _{DS} = 0 | _ | 1.0 | V |
| ON CHARACT | TERISTICS | | | | |
| I _{DSS} | Zero-Gate Voltage Drain Current (Note 4) | V _{DS} = 15 V, V _{GS} = 0 | 10 | 40 | mA |
| SMALL SIGNA | AL CHARACTERISTICS | | - | - | - |
| C _{iss} | Input Capacitance | V _{DS} = 15 V, V _{GS} = 0, f = 1.0 MHz | - | 16 | pF |
| C _{rss} | Reverse Transfer Capacitance | V _{GS} = -15 V, f = 1.0 MHz | _ | 6.0 | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse test with PW = 300 μ s, 1% duty cycle.

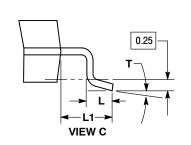


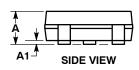
SOT-23 (TO-236) CASE 318-08 **ISSUE AS**

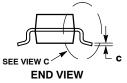
DATE 30 JAN 2018

SCALE 4:1 D – 3X h

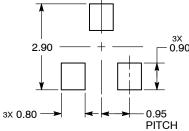
TOP VIEW







RECOMMENDED SOLDERING FOOTPRINT



DIMENSIONS: MILLIMETERS

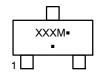
3. ANODE

NOTES:

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,

| | MILLIMETERS | | | | INCHES | |
|-----|-------------|------|------|-------|--------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| С | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| е | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| Т | 0° | | 10° | 0° | | 10° |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR | STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE | | |
|--|---|---|--|--|--|
| STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE | STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE | STYLE 11: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE | STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE | STYLE 13: PIN 1. SOURCE 2. DRAIN 3. GATE | STYLE 14: PIN 1. CATHODE 2. GATE 3. ANODE |
| STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE | STYLE 16: PIN 1. ANODE 2. CATHODE | STYLE 17: PIN 1. NO CONNECTION 2. ANODE 3. CATHODE | STYLE 18: PIN 1. NO CONNECTION 2. CATHODE 3. ANODE | STYLE 19: PIN 1. CATHODE 2. ANODE 3. CATHODE_ANODE | STYLE 20: PIN 1. CATHODE 2. ANODE |

| 2. CATHODE | 2. CATHODE | 2. ANODE | 2. CATHODE | 2. ANODE | 2. ANODE |
|-------------|---------------|--------------|-------------|----------------|----------------|
| 3. ANODE | 3. CATHODE | 3. CATHODE | 3. ANODE | 3. CATHODE-ANO | DDE 3. GATE |
| STYLE 21: | STYLE 22: | STYLE 23: | STYLE 24: | STYLE 25: | STYLE 26: |
| PIN 1. GATE | PIN 1. RETURN | PIN 1. ANODE | PIN 1. GATE | PIN 1. ANODE | PIN 1. CATHODE |
| 2. SOURCE | 2. OUTPUT | 2. ANODE | 2. DRAIN | 2. CATHODE | 2. ANODE |

| SOURCE DRAIN | 2. OUTPUT3. INPUT | ANODE CATHODE | 2. DRAIN 3. SOURCE | 2. CATHODE 3. GATE | 2. ANODE 3. NO CONNECTION |
|---|--|--|-----------------------|-----------------------|------------------------------|
| STYLE 27: PIN 1. CATHODE | STYLE 28: PIN 1. ANODE | | | | |
| 2. CATHODE | 2. ANODE | | | | |

| DOCUMENT NUMBER: | 98ASB42226B | Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. | |
|------------------|-----------------|---|-------------|
| DESCRIPTION: | SOT-23 (TO-236) | | PAGE 1 OF 1 |

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

3. CATHODE

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

 \Diamond